

Iterative Image Method for Apertureless THz Near-field Scanning Optical Microscopy based on the Analytic Image Theory

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Abstract—We propose a self-consistent iterative image method for apertureless THz near-field microscope (NFM) which is based on an analytic image theory. The probe tip and the sample nanoparticle are approximated as polarizable dielectric spheres. Within the quasi-electrostatic limit, the exact image theory was iteratively applied to calculate interactions between dielectric spheres and substrate effects. The result was in excellent agreement with result from a commercial finite element method (FEM) simulator (HFSS).

I. INTRODUCTION

SINCE the development of scanning probe microscopy, nano-science and technology have been intensively studied. Particularly near-field scanning optical microscopy (NSOM) can measure the nanoscale electromagnetic properties by the near-field interactions between the probe tip and a sample as well as the surface topology of a sample. Recently, THz pulse near-field microscopy (NFM) which combined conventional THz time-domain spectroscopy system with atomic force microscopy (AFM) was demonstrated by H. Park *et al* [1] and NFM using continuous wave THz source was reported by A. J. Huber *et al* [2].

In the conventional model for NSOM, both the probe tip and nanoparticles are represented by small polarizable dielectric spheres[3], and adopted a simple image theory to calculate the interaction between the probe tip and the sample sphere. However, the method is not self-consistent since the interactions between spheres and the substrate effect are not fully taken into account.

In this paper we propose a self-consistent semi-analytic scattering theory which is applicable to arbitrary numbers of particles on a substrate.

II. THEORY AND RESULTS

A. Theory

Suppose that there are two dielectric spheres each representing the tip and the sample nano-particle on a dielectric substrate, and an electric field is applied. If the spheres are located in close proximity to each other, then the simple dipole approximation does not give accurate results. Therefore, to calculate the scattered near-field of the THz NFM system, an alternative method is required.

Ignoring the interactions between the spheres, the induced

image dipole at the centers of a sphere by applied electric field $\vec{E}_0 = E_0 \hat{u}$ is calculated by:

$$\vec{p}_0 = \hat{u} 4\pi\epsilon_0 a^3 \frac{\epsilon_a - 1}{\epsilon_a + 2} E_0 \quad (1)$$

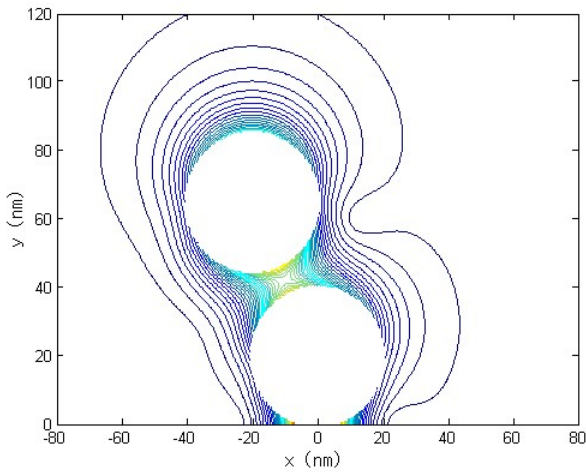
where a and ϵ_a represent the radius and the permittivity of the sphere, respectively. The induced image dipoles of the isolated spheres can be taken as zeroth-order terms for the iteration. The problem of a point dipole in front of a dielectric sphere was exactly solved by applying an image theory[4,5]. Therefore, the first-order image dipoles induced by the zeroth-order image dipoles can be calculated by adopting the exact image method by assuming the zeroth-order image dipoles as external dipole sources. The image dipoles induced in the substrate is calculated by the simple image theory for dielectric interfaces [6]. The second-order image dipoles can be calculated from the first-order image dipoles exactly in the same manner.

By applying the exact image method iteratively until the total induced dipole moment converges to a certain value, the complete dipole distribution which fully reflects existing interactions between the two spheres and the substrate can be obtained. The near-field profile can then be calculated from the calculated dipole distribution.

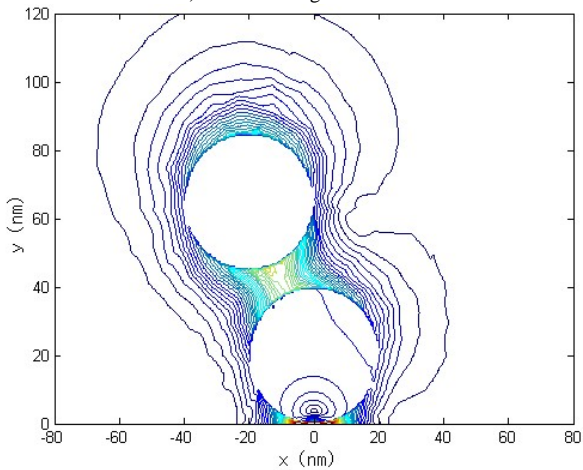
B. Results

The scattered near-field for THz NFM system has been calculated using the iterative image method and the HFSS, a commercial software based on the finite element method. The tungsten tip and the GaAs particle were approximated by dielectric spheres with diameter of 40 nm, and effects of the Au substrate were also included. The electric field polarized in the y-z plane is incident on the nanospheres with an incidence angle $\theta_{in} = 60^\circ$.

The scattered near-field distribution calculated using the iterative image method is shown in Fig.1. As expected, the THz near-field is strongly localized at the tip-to-sample gap by the interaction between the tip and the sample. The semi-analytic result from our self-consistent theory is in excellent agreement with the result from HFSS.



a) Iterative image method



b) Commercial FEM tool (HFSS).

Fig.1. The contour plot of near-field intensity for Tungsten and GaAs nanospheres on an Au substrate.

By simple extension of the iteration, it is simple to calculate near field distribution of a system with arbitrary numbers of spheres.

III. CONCLUSION

In summary, we have proposed a self-consistent iterative image theory for the apertureless THz NFM. The semi-analytic iteration method based on the exact image theory is equally applicable to other scattering problems with arbitrary numbers of nanospheres on a dielectric or metallic substrate.

ACKNOWLEDGEMENT

This work was supported by the Korea Science and Engineering Foundation through the National Research Laboratories Program (R0A-2005-005-J13103) and by the Korean Research Foundation through the Priority Research Centers Program (KRF-2005-005-J13103) and the Brain Korea 21 Project funded by the Ministry of Education, Science and Technology.

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